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APPLICATION NO.	FI	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/917,775	(	07/31/2001	Hisato Oyamatsu	002372.00027	1487	
22907	7590	05/22/2002				
BANNER &			EXAMINER			
1001 G STRI SUITE 1100			HU, SHOUXIANG			
WASHINGTON, DC 20001				ART UNIT	PAPER NUMBER	
				2811	-	
				DATE MAILED: 05/22/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)	<del>/\frac{\frac}\frac{\frac}{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac}}}}}{\frac{\fir}}}}}}{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{</del>
			09/917,775 OYAMATSU, HISATO	
	Office Action Summary	Examiner	Art Unit	
•	•	Shouxiang Hu	2811	
Period fo	Th MAILING DATE of this communicati n ap	_		addr ss
A SH THE I - Exter after - If the - If NO - Failu - Any r	ORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a repl period for reply is specified above, the maximum statutory period re to reply within the set or extended period for reply will, by statute eply received by the Office later than three months after the mailing ad patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however y within the statutory mini will apply and will expire Se, cause the application to	ver, may a reply be timely filed mum of thirty (30) days will be considered IX (6) MONTHS from the mailing date of become ABANDONED (35 U.S.C. § 133	this communication.
1)⊠	Responsive to communication(s) filed on 26	<u> April 2002</u> .		
2a) <u></u> □	This action is <b>FINAL</b> . 2b)⊠ Th	nis action is non-fir	al.	
3)□ Dispositi	Since this application is in condition for allow closed in accordance with the practice under on of Claims			to the merits is
4) 🛛	Claim(s) $\underline{1-15}$ is/are pending in the application	٦.		
	4a) Of the above claim(s) <u>2-7 and 9-15</u> is/are v	vithdrawn from cor	sideration.	
5) 🗌	Claim(s) is/are allowed.			
6)□	Claim(s) 1 and 8 is/are rejected.			
7)	Claim(s) is/are objected to.			
8)	Claim(s) are subject to restriction and/o	r election requiren	nent.	
Applicati	on Papers			
9)🖾 ¯	The specification is objected to by the Examine	r.		
10) 🔲 🗆	Γhe drawing(s) filed on is/are: a)□ acce	oted or b)⊡ objecte	d to by the Examiner.	
	Applicant may not request that any objection to th	e drawing(s) be held	in abeyance. See 37 CFR 1.85	ō(a).
11) 🔲 🗆	The proposed drawing correction filed on	_ is: a)□ approve	(b) disapproved by the Exa	aminer.
_	If approved, corrected drawings are required in re	•	on.	
12) 🔲 🛚	The oath or declaration is objected to by the Ex	aminer.		
Priority u	nder 35 U.S.C. §§ 119 and 120			
13)🛛	Acknowledgment is made of a claim for foreigr	n priority under 35	U.S.C. § 119(a)-(d) or (f).	
a)[	☑ All b)☐ Some * c)☐ None of:			
	1. Certified copies of the priority document	s have been recei	ved.	
	2. Certified copies of the priority document	s have been recei	ed in Application No	
	3. Copies of the certified copies of the prior application from the International Buree the attached detailed Office action for a list	reau (PCT Rule 17	7.2(a)).	onal Stage
14) 🗌 A	cknowledgment is made of a claim for domesti	c priority under 35	U.S.C. § 119(e) (to a provision	onal application).
a)	The translation of the foreign language procedures to the company of the foreign language procedures to the company of the com	visional applicatio	n has been received.	,
Attachment	(s)			
2) Notice 3) Inform	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) 3	5) 🔲 🛭	nterview Summary (PTO-413) Pape Notice of Informal Patent Application Other:	
S. Patent and Tra TO-326 (Rev		tion Summary	Р	art of Paper No. 8

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### **DETAILED ACTION**

1. Claims 2-7 and 9-15 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made **without** traverse in Paper No. 7.

Accordingly, claims 1-15 are pending in this application; and claims 1 and 8 remain active in this Office action.

## Claim Objections

2. Claims 1 and 8 are objected to because of the following informalities/defects:

The term of "facing" recited in claim 1 should read as --face-to-face--, to avoid potential misunderstandings.

Claim 8 recites "a well isolation structure," but fails to define the relationship between it and the "well isolation structure" defined in claim 1.

Appropriate correction is required.

# Claim Rejections - 35 USC § 112

- 3. The following is a quotation of the first paragraph of 35 U.S.C. 112:
  - The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.
- 4. Claim 8 is rejected under 35 U.S.C. 112, first paragraph, as based on a disclosure which is not enabling. The subject matter of "a well isolation structure having

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a narrower width than other circuit blocks" is critical or essential to the practice of the invention, but not enabled by the disclosure. See *In re Mayhew*, 527 F.2d 1229, 188 USPQ 356 (CCPA 1976). The disclosure fails to define what are the other circuit blocks and what is the positional relationship between the isolation structure corresponding to the opposed device regions and the isolation region corresponding to the other circuit blocks.

- 5. The following is a quotation of the second paragraph of 35 U.S.C. 112:
  The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 6. Claims 1 and 8 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claim 1 recites the subject matter that the first and second device regions are provided so as to be opposed at the first width and, when not meeting face-to-face, at the second width. But, it is indefinite because it is not physically possible for the same first and second device regions to be provided on the two sides of the isolation structure at the first width and the second width simultaneously, and to be opposed and not opposed simultaneously.

## Claim Rejections - 35 USC § 102

7. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

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(e) the invention was described in-

- (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).
- 8. Claim 1, insofar as being in compliance with 35 U.S.C. 112, is rejected under 35 U.S.C. 102(e) as being anticipated by Hirano 6,252,280).

Hirano discloses a semiconductor device (Figs. 1-3), comprising: first and second wells (7N and 7P); a well isolation structure in the form of a shallow trench (9; particularly see the PARTIAL ISOLATION REGION in Fig. 1); first and second device regions (8N and 8P), wherein the first and second device regions are provided so as to be opposed on the two sides of a portion of the isolation structure at a first width; and, the rest of the isolation structure has at least a second width larger than the first width and has no regions where the first and second device regions meet face-to-face.

# Claim Rejections - 35 USC § 103

- 9. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 10. Claim 8, insofar as in compliance with 35 U.S.C.112, is rejected under 35 U.S.C. 103(a) as being obvious over Hirano in view of Chan et al. ("Chan"; 6,091,630).

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The disclosure of Hirano is discussed as applied to claim 1 above.

The first and second device regions (8N and 8P) form a CMOS structure.

Although Hirano does not expressly disclose that such a CMOS structure can be used in static RAM as cell patterns, one of ordinary skill in the art would readily recognize that CMOS structure is one of the common structures used in the cell pattern of a static RAM, as evidenced in Chan (see Fig. 1).

Therefore, it would have been obvious to one of ordinary skilled in the art at the time the invention was made to make the CMOS structure of Hirano and applied it to cell patterns of a static RAM, as taught in Chan, so that a static RAM with desired CMOS performance would be obtained.

#### Conclusion

11. Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 or 308-7724. The Group 2811 Fax Center is to be used only for papers related to Group 2811 applications.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to *Shouxiang Hu* whose telephone number is **(703) 306-5729**. The examiner can normally be reached on Monday through Thursday from 7:30 AM to 6:00 PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, *Tom Thomas*, can be reached on (703) 308-2772. The appropriate fax phone number for the organization where this application or proceeding is assigned is (703) 308-7724.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center Receptionists** whose telephone number is **(703) 308-0956**.

Shouxiang Hu

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May 17, 2002